Not Recommended for New Design Alternative is BCP55 & BCP5516



DCP55/-16

NPN SURFACE MOUNT TRANSISTOR

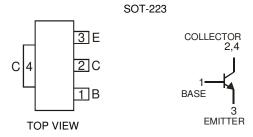
Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DCP52)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.115 grams (approximate)





Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	5	V
Peak Pulse Current	I _{CM}	1.5	Α
Continuous Collector Current	I _C	1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Power Dissipation @ T _A = 25°C	P _d	1 (Note 3)	W	
Fower Dissipation @ 1A = 23 C	га	2 (Note 4)	٧٧	
Operating and Storage Temperature Range	T_{j}, T_{STG}	-55 to +150	°C	
Thermal Resistance Junction to Ambient Air @ T _A = 25°C (Note 3)	$R_{\theta JA}$	125	°C/W	

Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 5)						
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60	_	_	V	$I_C = 100 \mu A, I_E = 0 A$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	60	_	_	V	$I_C = 10 \text{mA}, I_B = 0 \text{A}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5	_	_	V	$I_E = 10\mu A, I_C = 0A$
Collector Cut-Off Current	I _{CBO}	_	_	100	nA	$V_{CB} = 30V, I_{E} = 0A$
Collector Cut-On Current			_	20	μΑ	$V_{CB} = 30V, I_{E} = 0A, T_{A} = 150^{\circ}C$
Emitter Cut-Off Current	I _{EBO}		_	10	μΑ	$V_{EB} = 5V, I_{C} = 0A$
ON CHARACTERISTICS (Note 5)						
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		_	0.5	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage	V _{BE(ON)}		_	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 2V$
		40		250		$I_C = 150 \text{mA}, V_{CE} = 2V$
DC Current Gain	h _{FE}	25	_	_	_	$I_C = 500 \text{mA}, V_{CE} = 2V$
DCP55-16		100	_	250		I _C = 150mA, V _{CE} = 2V
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f⊤		200	_	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 5 \text{V},$ f = 100MHz

Note:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB pad layout as shown on page 4 or on Diodes, Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Device mounted on Polyimide PCB with a copper area of 1.8cm².
- 5. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%

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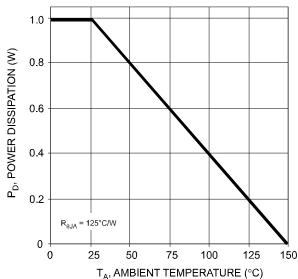


Fig. 1 Power Dissipation vs. Ambient Temperature

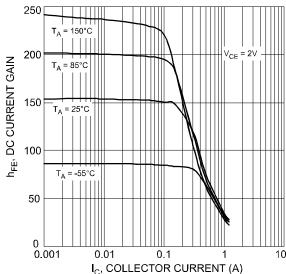
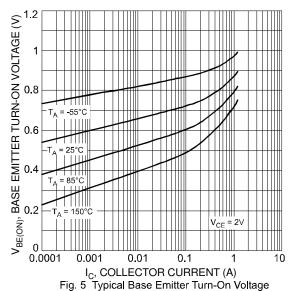
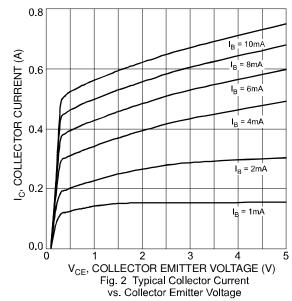


Fig. 3 Typical DC Current Gain vs. Collector Current



vs. Collector Current



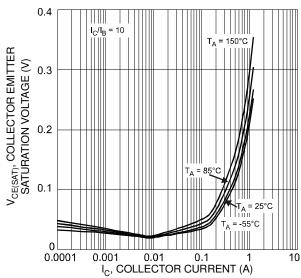


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

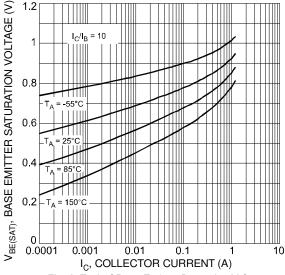
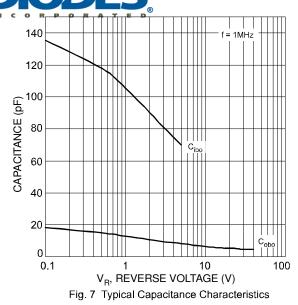


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current

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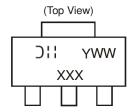
300 250 HLOMONDAMD 200 150 100 V_{CE} = 5V f = 100MHz 1_C, COLLECTOR CURRENT (mA) Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Ordering Information (Note 6)

Device	Packaging	Shipping
DCP55-13	SOT-223	2500 / Tape & Reel
DCP55-16-13	SOT-223	2500 / Tape & Reel

Note: 6. For packaging details, please visit our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

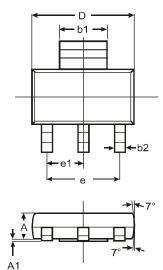


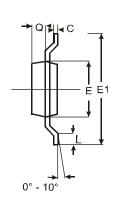
Oll = Manufacturer's code marking

XXX = Product type marking code Ex: N16 = DCP55

YWW = Date code marking Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

Package Outline Dimensions



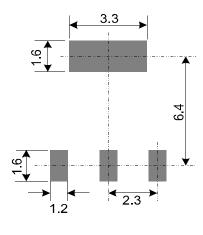


SOT-223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A 1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
e	_		4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

N16-16 = DCP55-16



Suggested Pad Layout: (Based on IPC-SM-782)



(Unit:mm)

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